L Number	Hits	Search Text	DB	Time stamp
1	1	257/$.ccls. and ((metal NEAR gate NEAR (layer film)) WITH (thermal NEAR oxide))	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2003/01/16 11:35
2	5	257/$.ccls. and ((metal NEAR gate) NEAR5 (thermal NEAR oxide))	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2003/01/16 11:38
3	6	257/$.ccls. and ((metal NEAR gate) WITH (thermal NEAR oxide))	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2003/01/16 11:39
4	3101	257/$.ccls. and (metal NEAR gate)	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2003/01/16 11:45
5	273	(257/$.ccls. and (metal NEAR gate)) and (thermal NEAR oxide)	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2003/01/16 11:45
6	1	((257/$.ccls. and (metal NEAR gate)) and (thermal NEAR oxide)) and (pre-metal NEAR dielectric)	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2003/01/16 11:45
7	172241	257/$.ccls.	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2003/01/16 11:44
10	1	((257/$.ccls. and (pre-metal NEAR dielectric)) and (metal NEAR gate)) and (thermal NEAR oxide)	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2003/01/16 11:45
9	2	(257/$.ccls. and (pre-metal NEAR dielectric)) and (metal NEAR gate)	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2003/01/16 11:46
8	49	257/$.ccls. and (pre-metal NEAR dielectric)	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2003/01/16 11:47